

DATA SHEET

NEC

NPN SILICON RF TRANSISTOR 2SC5180

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW-NOISE AMPLIFICATION 4-PIN SUPER MINIMOLD

FEATURES

- Low current consumption and high gain
 $|S_{21e}|^2 = 12 \text{ dB TYP. @ } V_{CE} = 2 \text{ V, } I_c = 7 \text{ mA, } f = 2 \text{ GHz}$
 $|S_{21e}|^2 = 11 \text{ dB TYP. @ } V_{CE} = 1 \text{ V, } I_c = 5 \text{ mA, } f = 2 \text{ GHz}$
- 4-pin super minimold Package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form
2SC5180	50 pcs (Non reel)	• 8 mm wide embossed taping • Pin 3 (Base), Pin 4 (Emitter) face to perforation side of the tape
2SC5180-T1	3 kpcs/reel	

Remark To order evaluation samples, contact your nearby sales office.
The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V _{CB0}	5	V
Collector to Emitter Voltage	V _{CE0}	3	V
Emitter to Base Voltage	V _{EB0}	2	V
Collector Current	I _c	10	mA
Total Power Dissipation	P _{tot} ^{Note}	30	mW
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Note Free air

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I _{CBO}	V _{CB} = 5 V, I _E = 0 mA	–	–	100	nA
Emitter Cut-off Current	I _{EBO}	V _{EB} = 1 V, I _C = 0 mA	–	–	100	nA
DC Current Gain	h _{FE} ^{Note 1}	V _{CE} = 2 V, I _C = 7 mA	70	–	140	–
RF Characteristics						
Gain Bandwidth Product (1)	f _T	V _{CE} = 2 V, I _C = 7 mA, f = 2.0 GHz	12	15.5	–	GHz
Gain Bandwidth Product (2)	f _T	V _{CE} = 1 V, I _C = 5 mA, f = 2.0 GHz	10	13	–	GHz
Insertion Power Gain (1)	S _{21e} ²	V _{CE} = 2 V, I _C = 7 mA, f = 2.0 GHz	10	12	–	dB
Insertion Power Gain (2)	S _{21e} ²	V _{CE} = 1 V, I _C = 5 mA, f = 2.0 GHz	8.5	11	–	dB
Noise Figure (1)	NF	V _{CE} = 2 V, I _C = 3 mA, f = 2.0 GHz	–	1.5	2.0	dB
Noise Figure (2)	NF	V _{CE} = 1 V, I _C = 3 mA, f = 2.0 GHz	–	1.5	2.0	dB
Reverse Transfer Capacitance	C _{re} ^{Note 2}	V _{CB} = 2 V, I _E = 0 mA, f = 1.0 MHz	–	0.3	0.5	pF

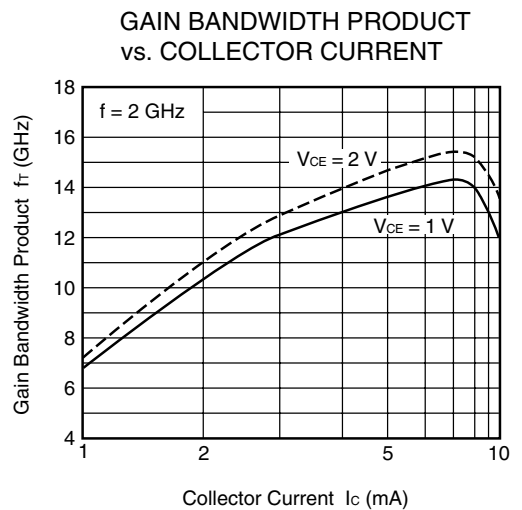
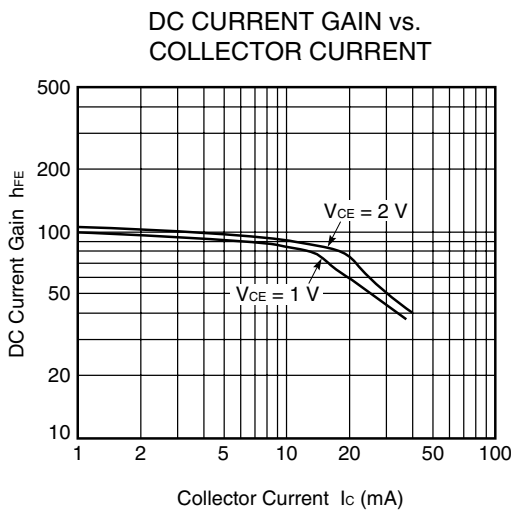
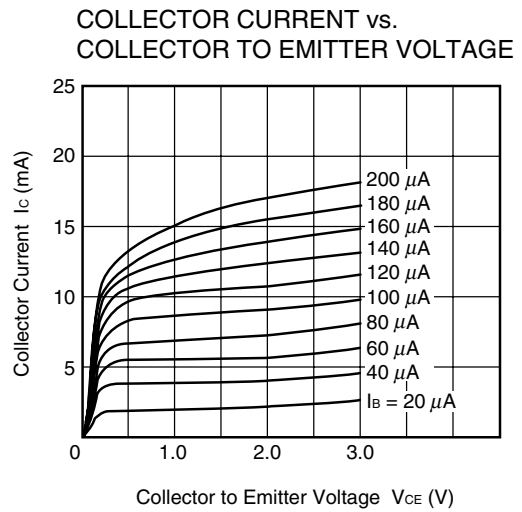
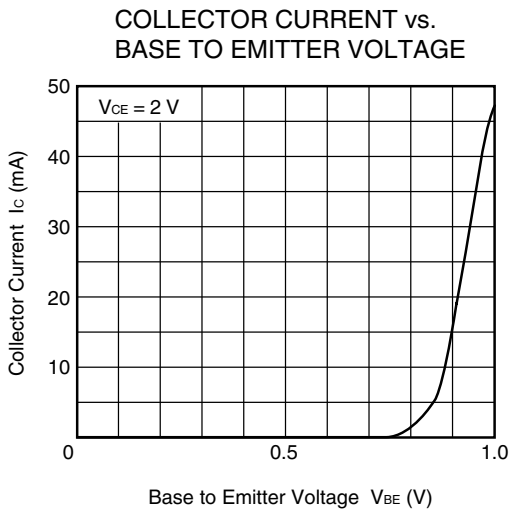
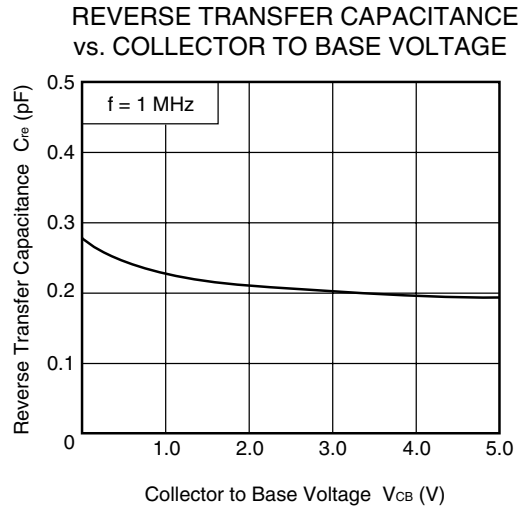
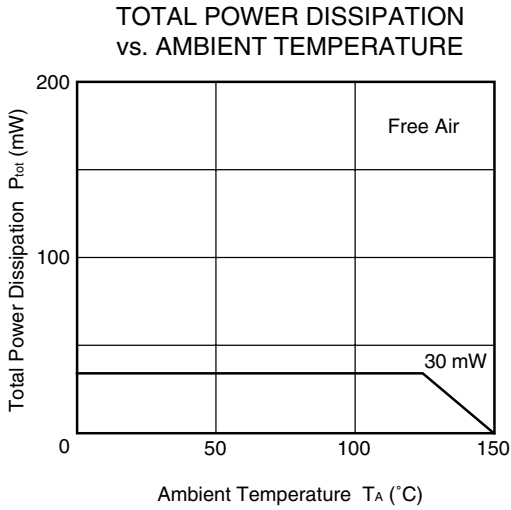
Notes 1. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%

2. Collector to base capacitance when the emitter grounded

h_{FE} CLASSIFICATION

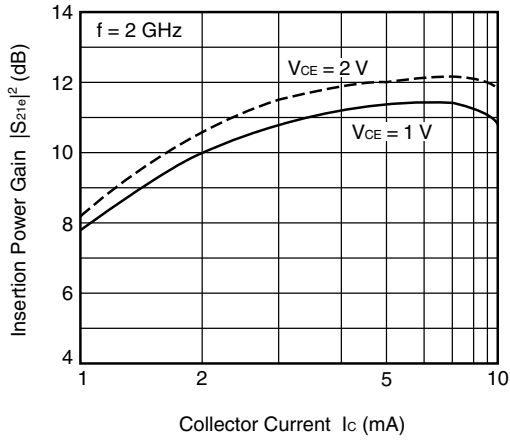
Rank	FB
Marking	T84
h _{FE} Value	70 to 140

TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)

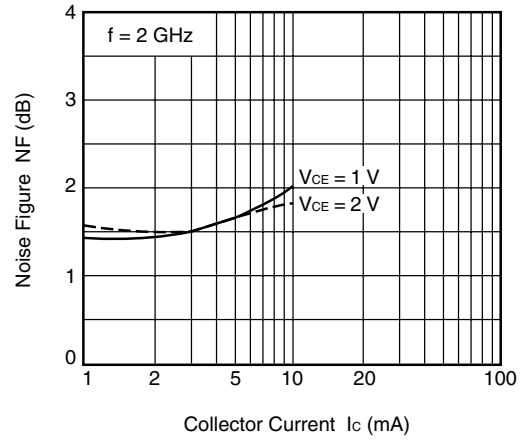


Remark The graphs indicate nominal characteristics.

INSERTION POWER GAIN vs. COLLECTOR CURRENT



NOISE FIGURE vs. COLLECTOR CURRENT



Remark The graphs indicate nominal characteristics.

★ **S-PARAMETERS**

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

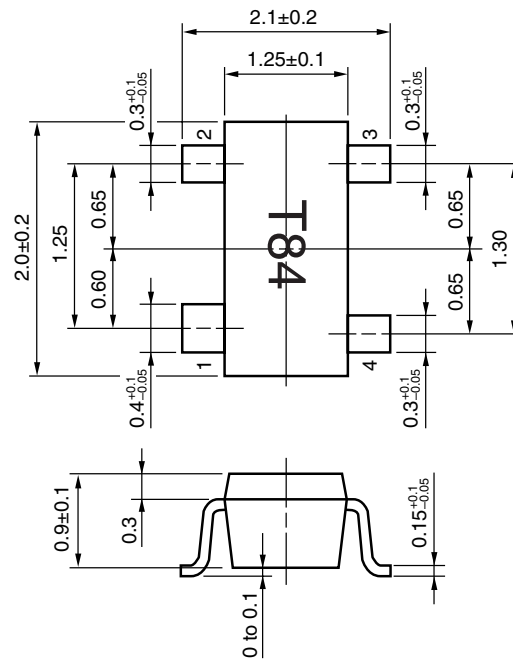
Click here to download S-parameters.

[RF and Microwave] → [Device Parameters]

URL <http://www.ncsd.necel.com/>

★ PACKAGE DIMENSIONS

4-PIN SUPER MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter

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